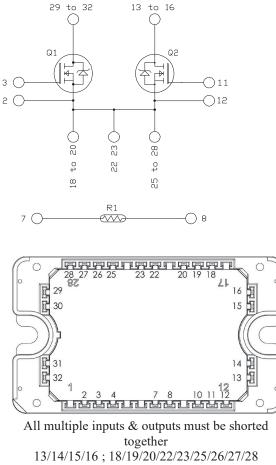


## **Dual Common Source SiC MOSFET Power Module**

### **Product Overview**

The MSCSM120DUM16T3AG device is a 1200V/173A dual common source silicon carbide (SiC) MOSFET power module.



; 29/30/31/32

All ratings at  $T_J$  = 25 °C, unless otherwise specified.

Δ CAUTION These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

## Features

The following are the key features of MSCSM120DUM16T3AG device:

- SiC Power MOSFET
  - Low R<sub>DS(on)</sub>
  - High temperature performance
- Kelvin source for easy drive
- Low stray inductance
- High level of integration
- Aluminum Nitride (AIN) substrate for improved thermal performance
- Internal thermistor for temperature monitoring

## Benefits

The following are the benefits of MSCSM120DUM16T3AG device:

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

## Application

The following are the applications of MSCSM120DUM16T3AG device:

AC switches

### 1. Electrical Specifications

This section provides the electrical specifications of the MSCSM120DUM16T3AG device.

### 1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings of MSCSM120DUM16T3AG device.

#### Table 1-1. Absolute Maximum Ratings

Symbol	Parameter		Maximum Ratings	Unit
V <sub>DSS</sub>	Drain-Source voltage	Source voltage 1		V
I <sub>D</sub>	Continuous drain current $T_{\rm C} = 2$		173	A
		T <sub>C</sub> = 80 °C	138	
I <sub>DM</sub>	Pulsed drain current		350	
V <sub>GSmax</sub>	Gate-Source voltage		-10/25	V
R <sub>DS(on)</sub>	Drain-Source ON resistance		16	mΩ
P <sub>D</sub>	Power dissipation	T <sub>C</sub> = 25 °C	745	W

The following table lists the electrical characteristics of MSCSM120DUM16T3AG device.

Symbol	Characteristic	Test Conditions		Min.	Тур.	Max.	Unit
I <sub>DSS</sub>	Zero gate voltage drain current	V <sub>GS</sub> = 0V V <sub>DS</sub> = 1200V		_	20	200	μΑ
R <sub>DS(on)</sub>	Drain–Source on resistance	V <sub>GS</sub> = 20V I <sub>D</sub> = 80A	T <sub>J</sub> = 25 °C T <sub>J</sub> = 175 °C	<u> </u>	12.5 20	16 —	mΩ
V <sub>GS(th)</sub>	Gate threshold voltage	$V_{GS} = V_{DS}$ $I_D = 2 \text{ mA}$		1.8	2.8	—	V
I <sub>GSS</sub>	Gate–Source leakage current	V <sub>GS</sub> = 20V V <sub>DS</sub> = 0V				200	nA

#### Table 1-2. Electrical Characteristics

**Electrical Specifications** 

The following table lists the dynamic characteristics of MSCSM120DUM16T3AG device.

Symbol	Characteristic	Test Conditions		Min.	Тур.	Max.	Unit
C <sub>iss</sub>	Input capacitance	VGS = 0V		-	6040	-	pF
C <sub>oss</sub>	Output capacitance	V <sub>DS</sub> = 1000V		—	540	-	-
C <sub>rss</sub>	Reverse transfer capacitance	f = 1 MHz		_	50	_	-
Qg	Total gate charge	V <sub>GS</sub> = -5V/20V		-	464	-	nC
Qgs	Gate-Source charge	V <sub>Bus</sub> = 800V		_	82	—	
Q <sub>gd</sub>	Gate-Drain charge	ID = 80A		-	100	-	
T <sub>d(on)</sub>	Turn-on delay time	$V_{GS} = -5V/20V$		_	30	_	ns
Tr	Rise time	V <sub>Bus</sub> = 600V		_	30	_	
T <sub>d(off)</sub>	Turn-off delay time	I <sub>D</sub> = 100A		_	50	_	
Τ <sub>f</sub>	Fall time	$R_{Gon} = 4\Omega$ $R_{Goff} = 2.4\Omega$			25	_	
Eon	Turn-on energy	V <sub>GS</sub> = -5V/20V	TJ = 150 °C	_	2.4	_	mJ
E <sub>off</sub>	Turn-off energy	$V_{Bus} = 600V$ $I_D = 100A$ $R_{Gon} = 4\Omega$ $R_{Goff} = 2.4\Omega$		_	1.3	_	
RGint	Internal gate resistance		_	2.94	_	Ω	
R <sub>th</sub> JC	Junction-to-case thermal	resistance		-	—	0.2	°C/W

#### Table 1-3. Dynamic Characteristics

The following table lists the body diode ratings and characteristics of MSCSM120DUM16T3AG device.

### Table 1-4. Body Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>SD</sub>	Diode forward voltage	V <sub>GS</sub> = 0V I <sub>SD</sub> = 80A		4		V
		V <sub>GS</sub> = -5V I <sub>SD</sub> = 80A	—	4.2	—	-
t <sub>rr</sub>	Reverse recovery time	I <sub>SD</sub> = 80A		90		ns
Q <sub>rr</sub>	Reverse recovery charge	$V_{GS} = -5V$		1100		nC
Irr	Reverse recovery current	V <sub>R</sub> = 800V di <sub>F</sub> /dt = 2000A/µs		27		A

### **Electrical Specifications**

### 1.2 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCSM120DUM16T3AG device.

Symbol	Characteristic			Min.	Max.	Unit
V <sub>ISOL</sub>	RMS isolation voltage, any terminal	RMS isolation voltage, any terminal to case t = 1 min, 50 Hz/60 Hz			—	V
TJ	Operating junction temperature range	Operating junction temperature range			175	°C
T <sub>JOP</sub>	Recommended junction temperature	Recommended junction temperature under switching conditions			T <sub>Jmax</sub> –25	
T <sub>STG</sub>	Storage case temperature			-40	125	
T <sub>C</sub>	Operating case temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package weight			_	110	g

#### Table 1-5. Thermal and Package Characteristics

The following table lists the temperature sensor NTC of the MSCSM120DUM16T3AG device.

#### Table 1-6. Temperature Sensor NTC

Symbol	Characteristic I		Min.	Тур.	Max.	Unit
R <sub>25</sub>	Resistance at 25 °C -		—	50	—	kΩ
$\Delta R_{25}/R_{25}$	—		—	5	_	%
B <sub>25/85</sub>	Т <sub>25</sub> = 298.15 К		_	3952	_	К
ΔΒ/Β	—	T <sub>C</sub> = 100 °C	—	4		%

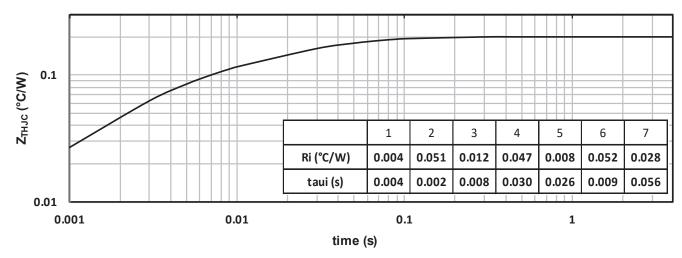
$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature T  
R<sub>T</sub>: Thermistor value at T

**Note:** See APT0406—Using NTC Temperature Sensor Integrated into Power Module for more information.

**Electrical Specifications** 

### 1.3 Typical SiC MOSFET Performance Curve (Per SiC MOSFET)

This section shows the typical SiC MOSFET performance curves of the MSCSM120DUM16T3AG device.



#### Figure 1-1. Maximum Thermal Impedance



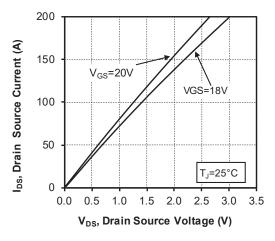
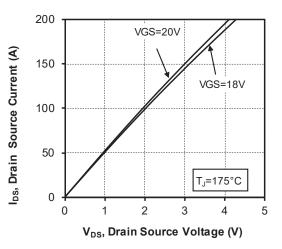


Figure 1-3. Output Characteristics,  $T_J$  = 175 °C



**Electrical Specifications** 



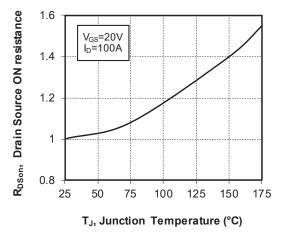
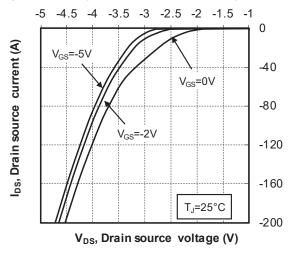


Figure 1-6. Body Diode Characteristics, T<sub>J</sub> = 25 °C





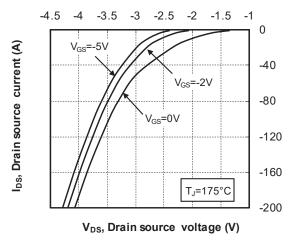


Figure 1-5. Transfer Characteristics

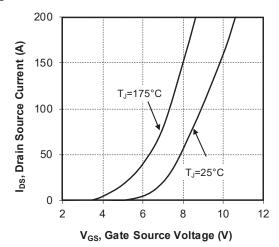
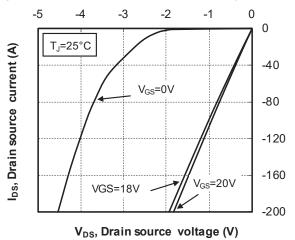
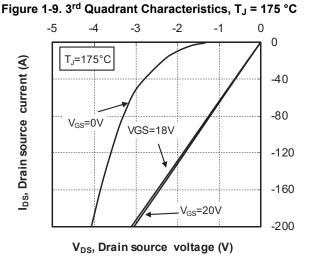


Figure 1-7. 3<sup>rd</sup> Quadrant Characteristics, T<sub>J</sub> = 25 °C





**Electrical Specifications** 

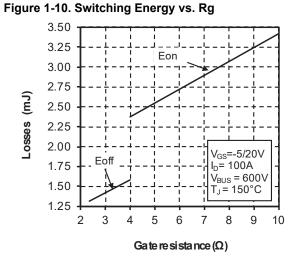


Figure 1-12. Operating Frequency vs. Drain Current

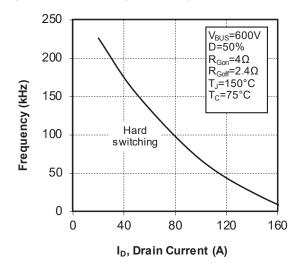
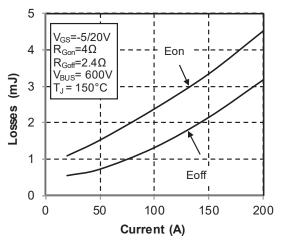


Figure 1-11. Switching Energy vs. Current



### Package Specifications

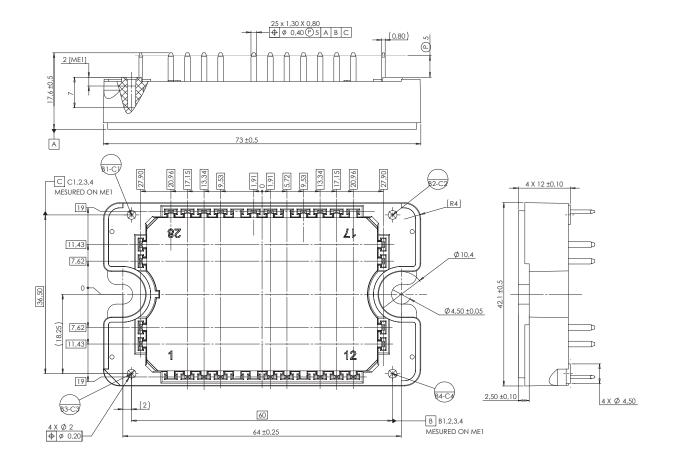
### 2. Package Specifications

The following section shows the package specification of the MSCSM120DUM16T3AG device.

### 2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM120DUM16T3AG device. The dimensions in the following figure are in millimeters.

#### Figure 2-1. Package Outline Drawing



**Note:** See application note AN3500A—Mounting Instructions for SP1F and SP3F Power Modules for more information.

## 3. Revision History

Revision	Date	Description
Α	12/2021	Initial Revision

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